Silicon NPN Epitaxial

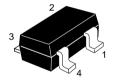
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Application

VHF and UHF wide band amplifier

Outline

MPAK-4



- 1. Collector
- 2. Emitter
- 3. Base
- 4. Emitter



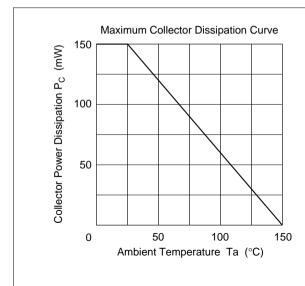
Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

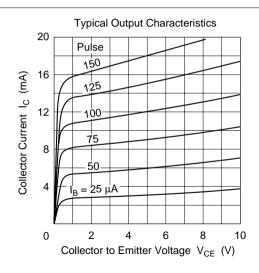
Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	15	V
Collector to emitter voltage	V _{CEO}	11	V
Emitter to base voltage	V_{EBO}	2	V
Collector current	I _c	50	mA
Collector power dissipation	P _c	150	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

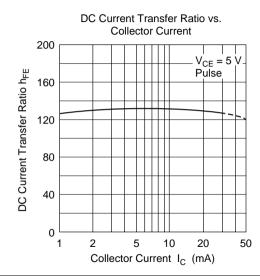
Electrical Characteristics ($Ta = 25^{\circ}C$)

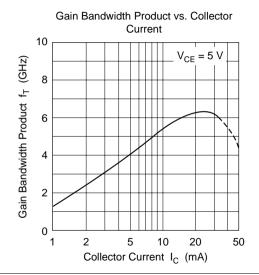
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	15	_	_	V	$I_{C} = 10 \ \mu A, \ I_{E} = 0$
Collector cutoff current	I _{CBO}	_	_	1	μΑ	$V_{CB} = 12 \text{ V}, I_{E} = 0$
	I _{CEO}	_	_	1	μΑ	$V_{CE} = 10 \text{ V}, R_{BE} = \infty$
Emitter cutoff current	I _{EBO}	_	_	1	μΑ	$V_{EB} = 1 V, I_C = 0$
DC current transfer ratio	h_{FE}	50	_	250		$V_{CE} = 5 \text{ V}, I_{C} = 20 \text{ mA}$
Collector output capacitance	Cob	_	1.0	1.5	pF	$V_{CB} = 5 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$
Gain bandwidth product	$f_{\scriptscriptstyle T}$	4.5	6.0	_	GHz	$V_{CE} = 5 \text{ V}, I_{C} = 20 \text{ mA}$
Power gain	PG	9.0	11.0	_	dB	$V_{CE} = 5 \text{ V}, I_{C} = 20 \text{ mA},$ f = 900 MHz
Noise figure	NF	_	1.5	3.0	dB	$V_{CE} = 5 \text{ V}, I_{C} = 5 \text{ mA},$ f = 900 MHz

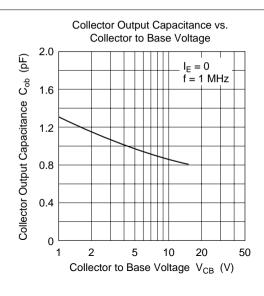
Note: Marking is "MI-".

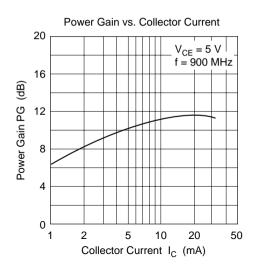


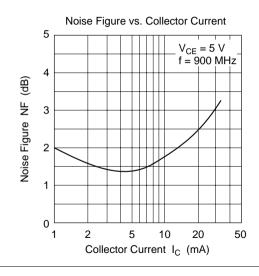






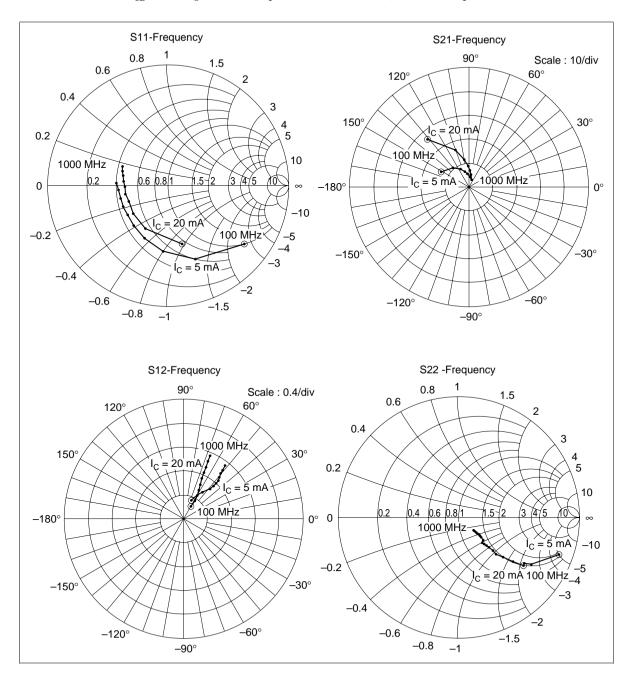






S Parameters (Emitter Common)

Test condition $V_{CE} = 5 \text{ V}, Z_{O} = 50 \Omega, \text{ Freq.} = 100 \text{ to } 1000 \text{ MHz (} 100 \text{ MHz Step)}$



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S Parameters (Emitter Common)

 $\mbox{Test condition} \quad V_{CE} \, = 5 \ V, \, I_C = 5 \ mA, \, Z_O = 50 \ \Omega$

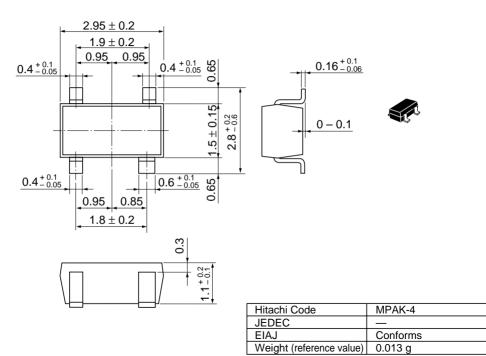
Freq. (MHz)	S ₁₁	∠S₁₁ (DEG.)	S ₂₁	∠S ₂₁ (DEG.)	S ₁₂	∠S ₁₂ (DEG.)	S ₂₂	∠S₂₂ (DEG.)	Gmax* ¹ (dB)
100	0.798	-37.3	13.345	152.3	0.033	69.6	0.898	-20.1	34.03
200	0.659	-69.4	10.696	131.4	0.054	56.0	0.730	-33.1	26.37
300	0.550	-93.7	8.434	117.0	0.067	49.2	0.592	-39.3	21.96
400	0.480	-113.6	6.815	107.3	0.074	47.3	0.502	-42.3	19.07
500	0.438	-129.8	5.684	100.0	0.081	47.0	0.442	-43.7	16.96
600	0.414	-143.6	4.847	94.2	0.087	47.3	0.399	-44.4	15.28
700	0.410	-154.4	4.229	89.4	0.092	48.6	0.366	-45.3	13.95
800	0.406	-164.7	3.750	85.0	0.098	49.5	0.340	-46.3	12.80
900	0.412	-174.9	3.352	81.0	0.104	50.6	0.317	-47.4	11.78
1000	0.424	-178.1	3.071	77.4	0.110	51.6	0.299	-48.3	11.01

Test condition $V_{CE} = 5~V,~I_C = 20~mA,~Z_O = 50~\Omega$

Freq. (MHz)	S ₁₁	∠S ₁₁ (DEG.)	S ₂₁	∠S₂₁ (DEG.)	S ₁₂	∠S ₁₂ (DEG.)	S ₂₂	∠S ₂₂ (DEG.)	Gmax* ¹ (dB)
100	0.501	-75.1	26.789	131.8	0.024	62.2	0.683	-36.5	32.54
200	0.402	-117.1	16.600	111.1	0.035	58.5	0.446	-45.4	26.13
300	0.368	-141.0	11.543	100.7	0.044	61.3	0.337	-45.6	22.40
400	0.347	-157.6	8.823	94.7	0.054	63.3	0.282	-44.2	19.83
500	0.354	-169.0	7.131	89.5	0.063	65.0	0.250	-42.8	17.92
600	0.358	-178.7	5.979	85.8	0.074	66.6	0.228	-42.1	16.36
700	0.370	174.9	5.158	82.3	0.084	66.9	0.208	-42.1	15.08
800	0.380	167.1	4.536	79.2	0.094	67.3	0.192	-42.7	13.98
900	0.400	161.5	4.042	76.5	0.104	67.6	0.178	-43.2	13.03
1000	0.411	157.0	3.677	73.5	0.114	67.4	0.165	-43.3	12.24

Note: 1.
$$Gmax = \frac{1}{\left|1 - \left|S_{11}\right|^2\right|} \cdot \left|S_{21}\right|^2 \cdot \frac{1}{\left|1 - \left|S_{22}\right|^2\right|}$$

Unit: mm



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